



CAT3606

6-Channel Low Noise Charge Pump White LED Driver

FEATURES

- Drives up to 4 main LEDs and 2 sub LEDs
- Separate control for main and sub LEDs
- Compatible with supply voltage of 3V to 5.5V
- Power efficiency up to 90%
- Output current up to 30mA per LED
- High-frequency Operation at 1MHz
- 2 modes of operation 1x and 1.5x
- White LED detect circuitry on all channels
- Shutdown current less than 1μA
- Small ceramic capacitors
- Soft start and current limiting
- Short circuit protection
- 16-lead thin QFN package, 0.8mm max height

APPLICATIONS

- Cell phone main and sub-display backlight
- Navigation
- PDAs
- Digital Cameras

DESCRIPTION

The CAT3606 controls up to four LEDs for the main display and two LEDs for the sub-display in cellular phones. The device is capable of operating in either 1x (LDO) mode or 1.5x charge pump mode. All LED pin currents are regulated and tightly matched to achieve uniformity of brightness across the LCD backlight. An external resistor (R_{SET}) sets the nominal output current.

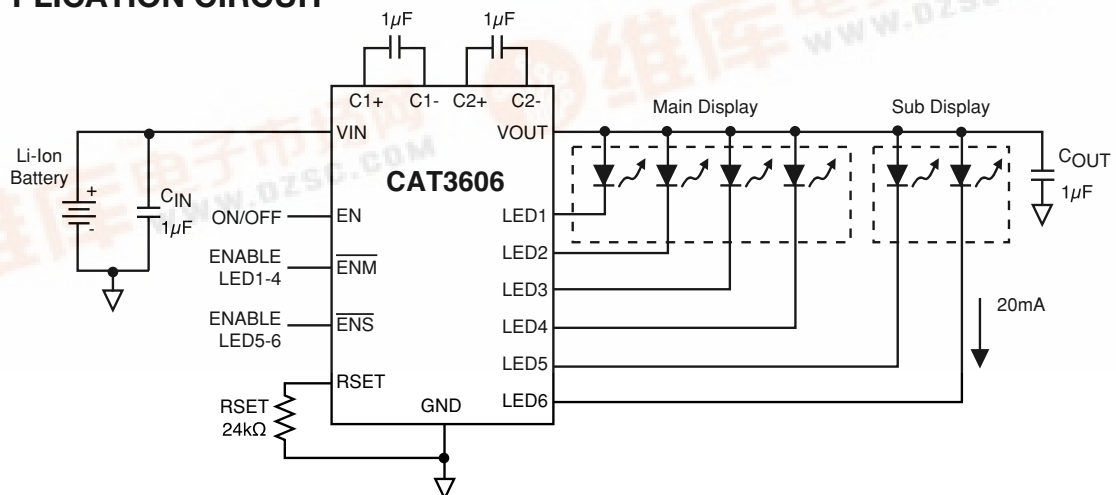
The device can deliver as much as 20mA per channel during low voltage operation (3V), and 30mA per channel during nominal operation (3.3V). A constant high-frequency switching scheme

(1MHz) provides low noise and allows the use of very small value ceramic capacitors.

A “zero” quiescent current mode can be achieved via the chip enable pin EN. The Main and Sub LEDs each have their own dedicated ON/OFF control pins ($\overline{\text{ENM}}$, $\overline{\text{ENS}}$). Dimming can be achieved using either a DC voltage to control the R_{SET} pin current, or by applying a PWM signal on the $\overline{\text{ENM}}$ and $\overline{\text{ENS}}$ pins.

The device is available in a 16-lead thin QFN package with a max height of 0.8mm.

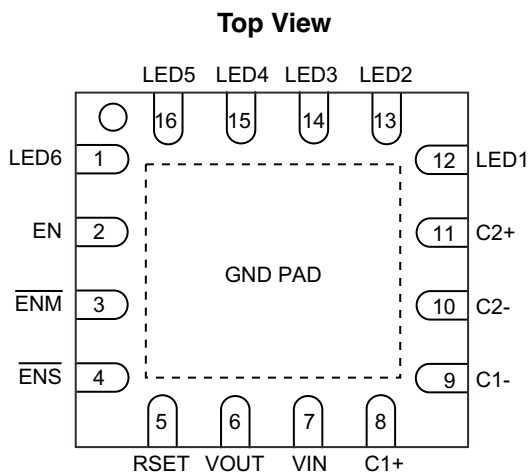
TYPICAL APPLICATION CIRCUIT



ORDERING INFORMATION

Part Number	Package	Quantity per Reel	Package Marking
CAT3606HS4	Thin QFN-16 4x4mm	2000	C366
CAT3606HV4	Thin QFN-16 4x4mm Lead Free	2000	G366

PIN CONFIGURATION



16-lead Thin QFN (4mm x 4mm)

Note: The "exposed pad" under the package must be connected to the ground plane on the PCB.

PIN DESCRIPTIONS

Pin Number	Name	Function
1	LED6	LED6 cathode terminal
2	EN	Enable/shutdown input, active high
3	ENM	Enable "main" input for LED1 to LED4, active low
4	ENS	Enable "sub" input for LED5 and LED6, active low
5	RSET	The LED output current is set by the current sourced out of the RSET pin
6	VOUT	Charge pump output connected to the LED anodes
7	VIN	Supply voltage
8	C1+	Bucket capacitor 1 terminal
9	C1-	Bucket capacitor 1 terminal
10	C2-	Bucket capacitor 2 terminal
11	C2+	Bucket capacitor 2 terminal
12	LED1	LED 1 cathode terminal
13	LED2	LED 2 cathode terminal
14	LED3	LED 3 cathode terminal
15	LED4	LED 4 cathode terminal
16	LED5	LED 5 cathode terminal
PAD	GND	Ground reference

ABSOLUTE MAXIMUM RATINGS

Parameter	Rating	Unit
VIN, VOUT, LEDx voltage	-0.3 to 7.0	V
EN, ENM, ENS voltage	-0.3 to VIN	V
RSET voltage	-0.3 to VIN	V
RSET current	±1	mA
Ambient Temperature Range	-40 to +85	°C
Storage Temperature Range	-65 to +160	°C
Lead Temperature	300	°C
ESD Ratings		
Human Body Model (HBM)	2000	V
Machine Model (MM) (note 1)	200	V

Note 1: Machine model is with 200pF capacitor discharged directly into each pin.

RECOMMENDED OPERATING CONDITIONS

Parameter	Rating	Unit
VIN	3.0 to 5.5	V
Ambient Temperature Range	-40 to +85	°C
Input/Output/Bucket Capacitors	1 ±20% typical	μF
I _{LED} per LED pin	0 to 30	mA
I _{OUT} Total Output Current	0 to 150	mA

ELECTRICAL OPERATING CHARACTERISTICS

Limits over recommended operating conditions unless specified otherwise. Typical values at T_A = 25°C, VIN = 3.5V, I_{RSET} = 5μA.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
I _Q	Quiescent Current	V _{EN} = 0V 1x Mode, No Load 1.5x Mode, No Load		0.1 0.3 2.6	1 1 5	μA mA mA
V _{RSET}	RSET Regulated Voltage		1.17	1.2	1.23	V
I _{LED}	Programmed LED Current	I _{RSET} = 5μA I _{RSET} = 37μA I _{RSET} = 78μA		2.4 15.0 30.0		mA mA mA
I _{LED}	LED Current Range with 6 LEDs	3.3 ≤ VIN ≤ 4.5 V 3.0 ≤ VIN ≤ 4.5 V			30 20	mA mA
I _{LED}	LED Current Range with 4 LEDs	3.0 ≤ VIN ≤ 4.5V			30	mA
I _{LED-ACC}	LED Current Accuracy	0.5mA ≤ I _{LED} ≤ 3mA 3mA ≤ I _{LED} ≤ 30mA		±15 ±5		% %
I _{LED-DEV}	LED Channel Matching	(I _{LED} - I _{LEDAVG}) / I _{LEDAVG}		±3		%
R _{OUT}	Output Resistance (Open Loop)	1x Mode 1.5x Mode, I _{OUT} = 100mA		1.4 6.5	2.5 10	Ω Ω
f _{OSC}	Charge Pump Frequency		0.8	1.0	1.3	MHz
T _{DROPOUT}	1x to 1.5x Mode Transition Dropout Delay		0.4	0.6	0.9	ms
I _{EN-CTR}	Input Leakage Current	On Inputs EN, ENM, ENS			1	μA
V _{EN-CTR}	High Detect Threshold Low Detect Threshold	On Inputs EN, ENM, ENS	0.4	0.8 0.7	1.3	V V
I _{SC}	Input Current Limit	VOUT = GND	30	45	60	mA
I _{LIM}	Maximum Input Current	VOUT > 1V	200	400	600	mA

The enable lines $\overline{\text{ENM}}$ and $\overline{\text{ENS}}$ allow to turn On or Off a group of LEDs as shown in Table 2.

Control Lines			LED Outputs	
EN	$\overline{\text{ENM}}$	$\overline{\text{ENS}}$	Main LED1 - LED4	Sub LED5 - LED6
0	X	X	-	-
1	1	1	-	-
1	0	1	ON	-
1	1	0	-	ON
1	0	0	ON	ON

Table 2: LED Selection

Notes: 1 = logic high (or VIN)
 0 = logic low (or GND)
 - = LED output OFF
 X = don't care

The unused LED channels can also be turned off by connecting the respective LED pins to VOUT. In which case, the corresponding LED driver is disabled and the typical LED sink current is only about 0.2mA. When the following equation is true on any channel, the driver turns off the LED channel:

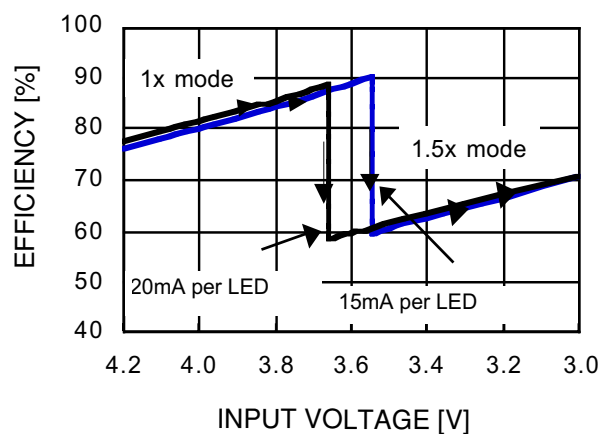
$$\text{VOUT} - \text{V}_{\text{LED}} \leq 1\text{V (LED channel OFF)}$$

Note: The CAT3606 is designed to drive LEDs with forward voltage greater than 1V and is not compatible with resistive loads.

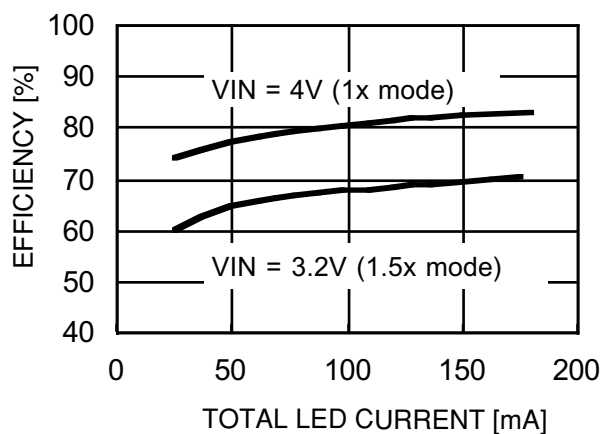
TYPICAL CHARACTERISTICS

$V_{IN} = 3.6V$, $EN = \overline{VIN}$, $\overline{ENM} = \overline{ENS} = GND$, $C_{IN} = C_{OUT} = 1\mu F$, $R_{SET} = 24k\Omega$ (20mA per LED), $T_{AMB} = 25^\circ C$, unless otherwise specified.

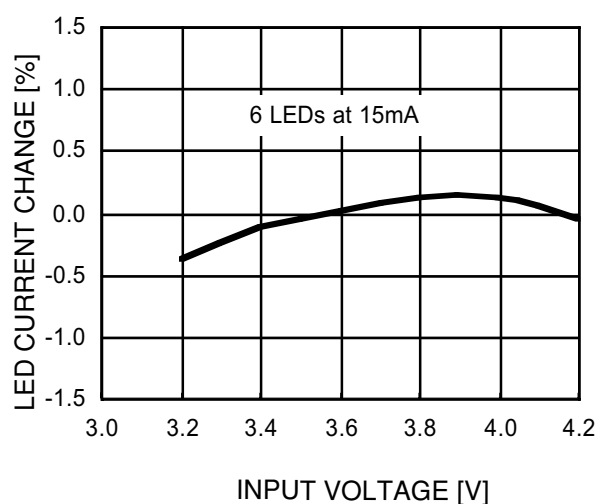
Efficiency vs. Input Voltage (6 LEDs)



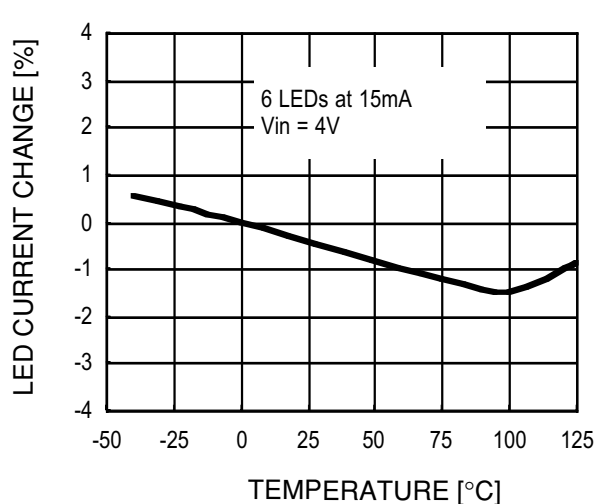
Efficiency vs. Total LED Current (6 LEDs)



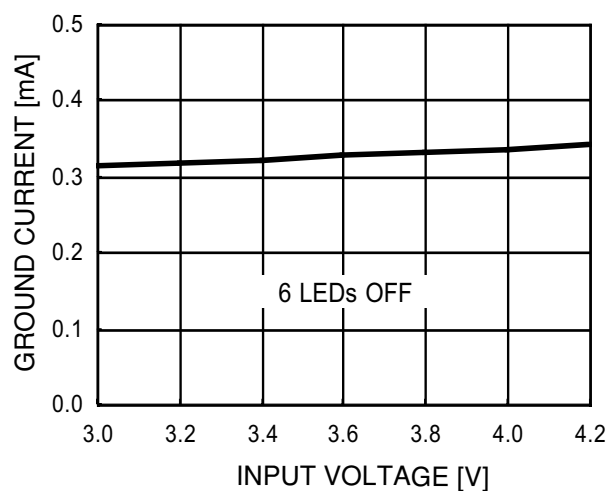
LED Current Change vs. Input Voltage



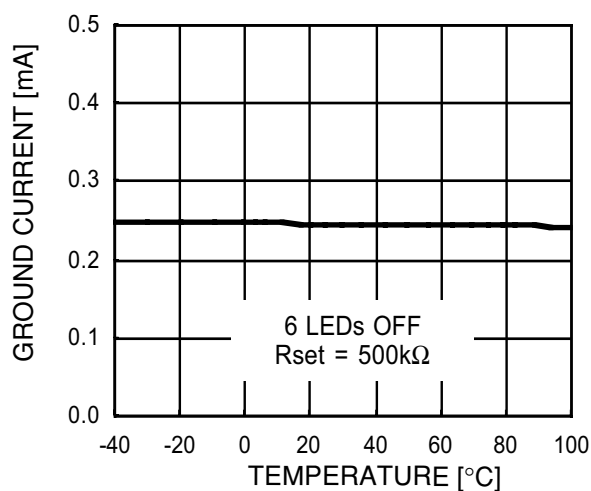
LED Current Change vs. Temperature



Ground Current vs. Input Voltage (1x mode)



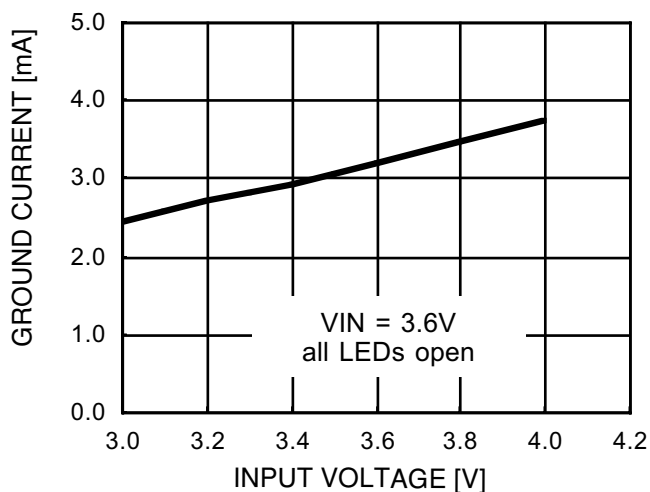
Ground Current vs. Temperature (1x mode)



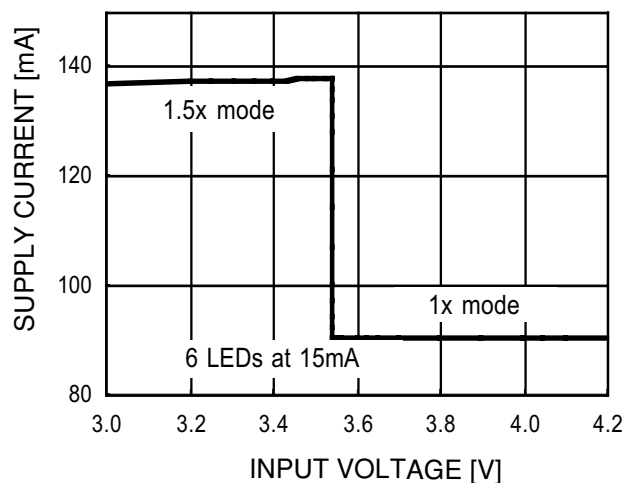
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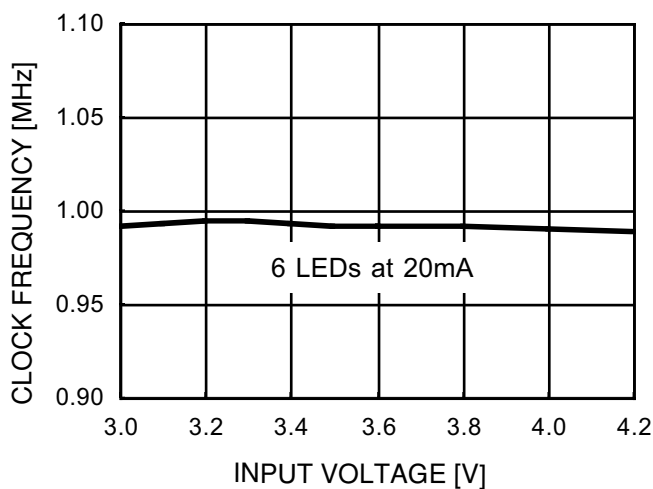
Ground Current vs. Input Voltage (1.5x mode)



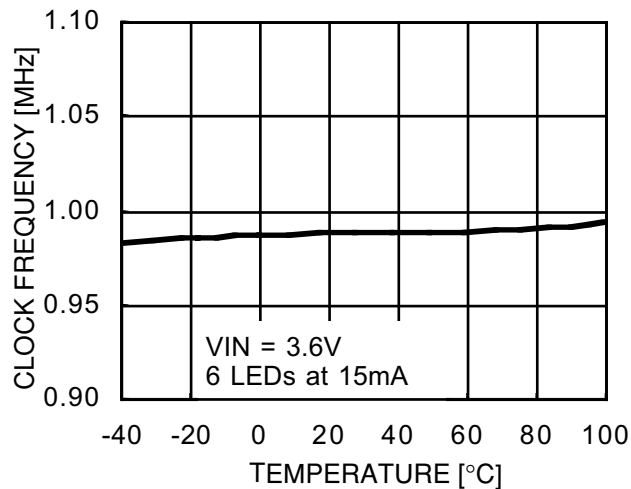
Supply Current vs. Input Voltage



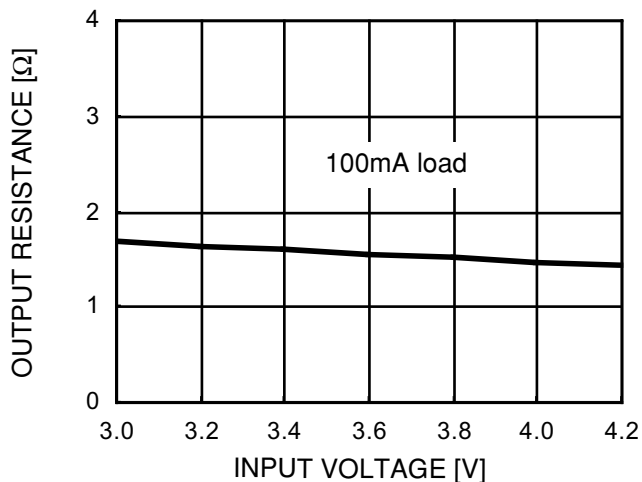
Oscillator Frequency vs. Input Voltage



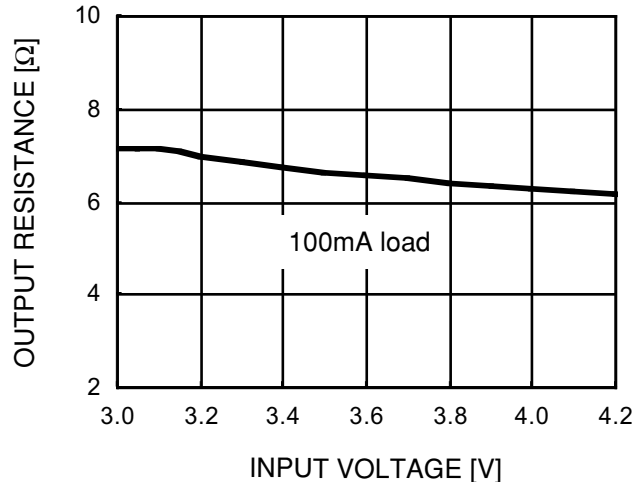
Oscillator Frequency vs. Temperature



Output Resistance vs. Input Voltage (1x mode)



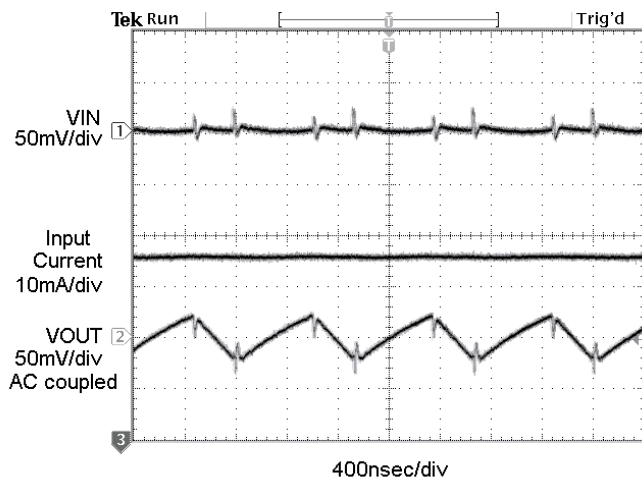
Output Resistance vs. Input Voltage (1.5x mode)



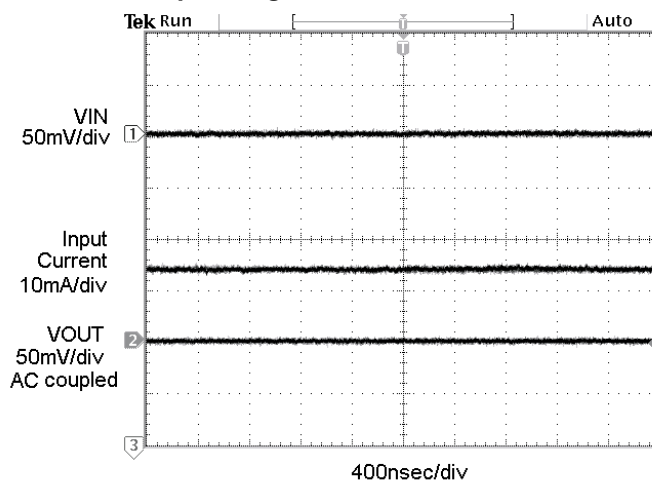
TYPICAL CHARACTERISTICS

$V_{IN} = 3.6V$, $EN = \overline{VIN}$, $\overline{ENM} = \overline{ENS} = GND$, $C_{IN} = C_{OUT} = 1\mu F$, $R_{SET} = 24k\Omega$ (20mA per LED), $T_{AMB} = 25^\circ C$, unless otherwise specified.

Switching Waveforms in 1.5x Mode

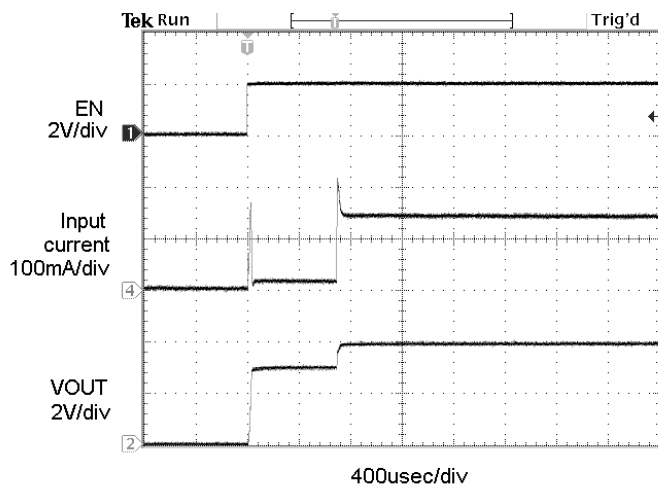


Operating Waveforms in 1x Mode

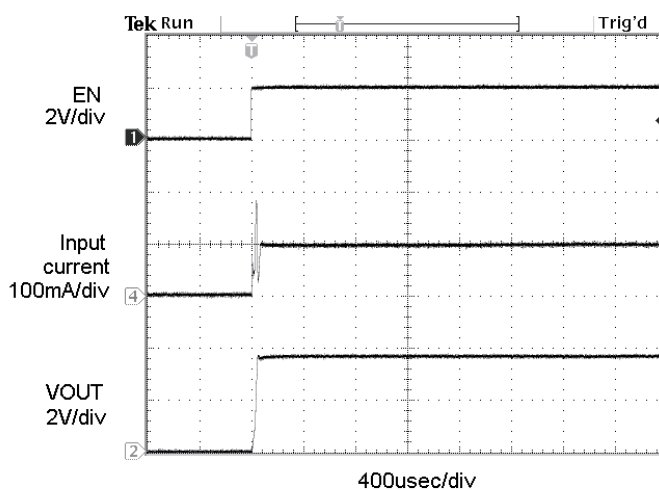


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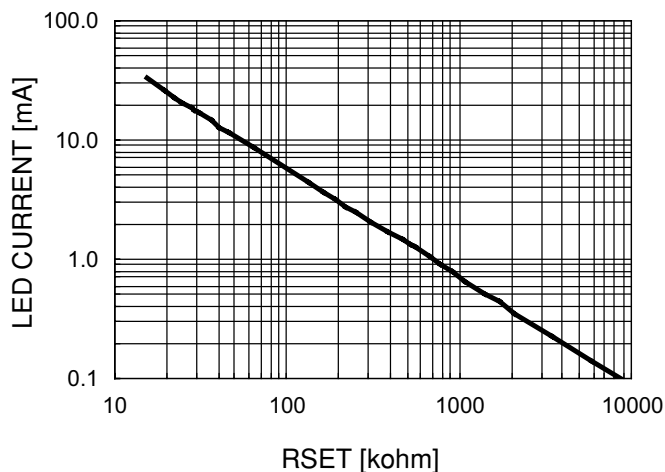
Power Up 6 LEDs at 15mA, $V_{IN} = 3V$ (1.5x Mode)



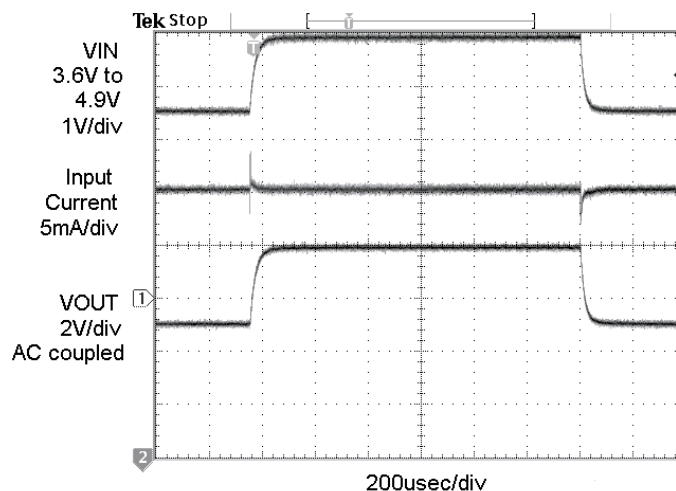
Power Up 6 LEDs at 15mA, $V_{IN} = 3.6V$ (1x Mode)



LED Current vs. R_{SET}



Line Transient Response in 1x Mode



VIN = 3.6V, EN = VIN, $\overline{\text{ENM}} = \overline{\text{ENS}} = \text{GND}$, C_{IN} = C_{OUT} = 1μF, T_{AMB} = 25°C, unless otherwise specified.

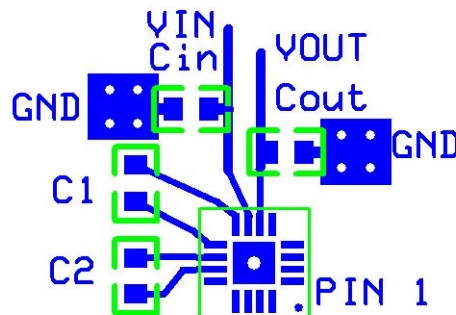
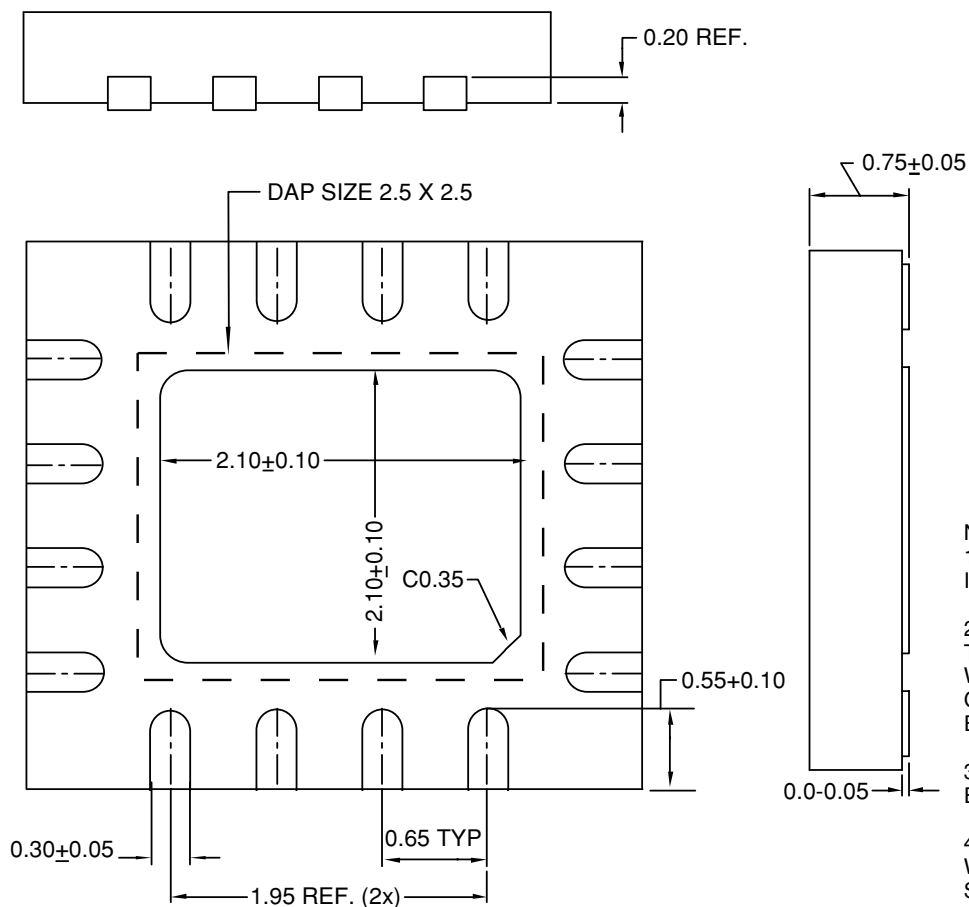
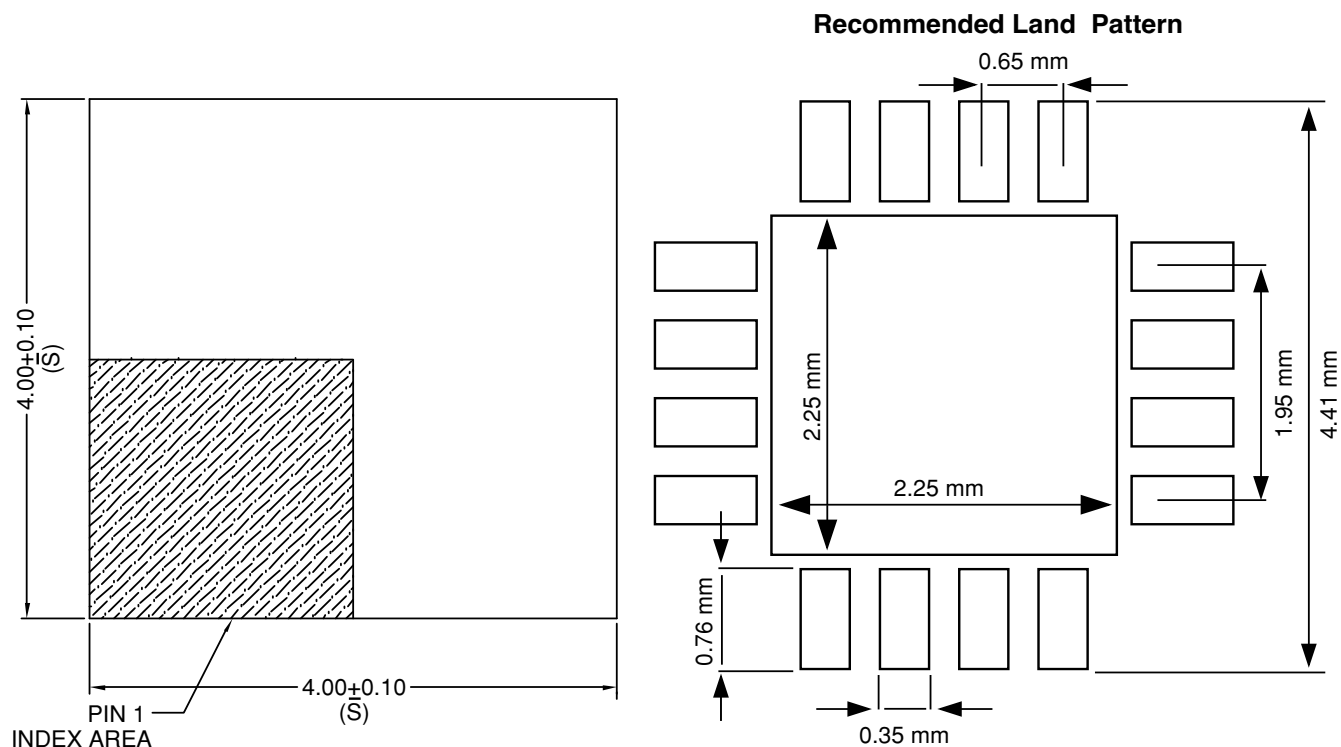


Figure 2: PCB Layout

PACKAGE DRAWING AND DIMENSIONS

THIN QFN 16-LEAD 4MM X 4MM



NOTE:
 1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES.

2. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS. COPLANARITY SHALL NOT EXCEED 0.08mm.

3. WARPAGE SHALL NOT EXCEED 0.10mm.

4. PACKAGE LENGTH/PACKAGE WIDTH ARE CONSIDERED AS SPECIAL CHARACTERISTIC. (S)

REVISION HISTORY

Date	Rev.	Reason
1/21/2005	A	Initial issue
08/01/2005	B	Update LED Current Setting

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